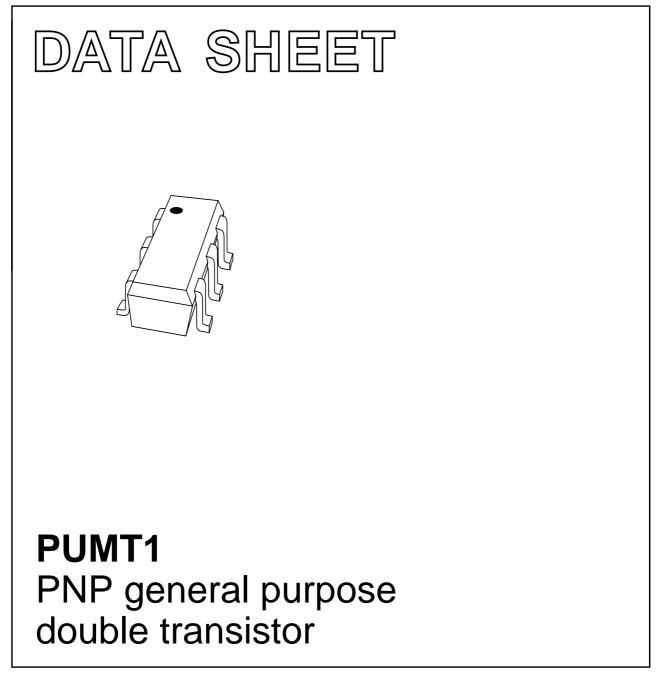
DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1999 Apr 14 2001 Dec 19



FEATURES

- Low current (max. 100 mA)
- Low voltage (max. 40 V)
- Reduces number of components and boardspace.

APPLICATIONS

• General purpose switching and amplification.

DESCRIPTION

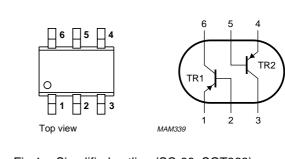
Two independently operating PNP transistors in an SC-88; SOT363 plastic package. NPN complement: PUMX1.

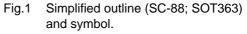
MARKING

TYPE NUMBER	MARKING CODE
PUMT1	FtF

PINNING

PIN	DESCRIPTION	
1, 4	emitter	TR1; TR2
2, 5	base	TR1; TR2
3, 6	collector	TR2; TR1





LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	PARAMETER CONDITIONS		MAX.	UNIT
Per transist	tor	·			
V _{CBO}	collector-base voltage	open emitter	_	-50	V
V _{CEO}	collector-emitter voltage	-emitter voltage open base		-40	V
V _{EBO}	emitter-base voltage	open collector	_	-5	V
I _C	collector current (DC)		_	-100	mA
I _{CM}	peak collector current		_	-200	mA
I _{BM}	peak base current		_	-200	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	_	200	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C
Per device		·		•	
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	_	300	mW

Note

1. Device mounted on an FR4 printed-circuit board.

PUMT1

PUMT1

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT	
Per device					
R _{th j-a}	thermal resistance from junction to ambient	note 1	416	K/W	

Note

1. Device mounted on an FR4 printed-circuit board.

CHARACTERISTICS

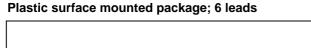
 T_{amb} = 25 °C; unless otherwise specified.

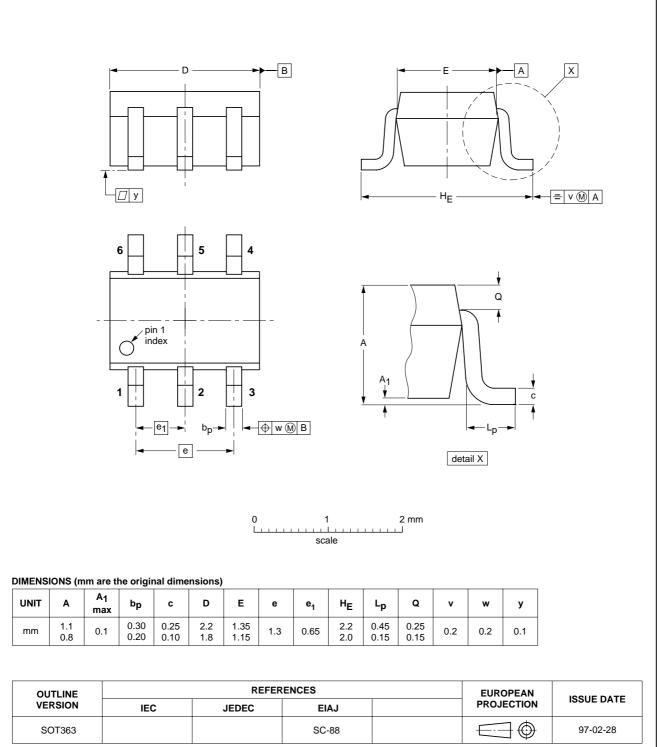
SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per transist	Per transistor				
I _{CBO}	collector cut-off current	$I_{E} = 0; V_{CB} = -30 V$	_	-100	nA
		I _E = 0; V _{CB} = -30 V; T _j = 150 °C	-	-10	μA
I _{EBO}	emitter cut-off current	$I_{\rm C} = 0; V_{\rm EB} = -4 \text{ V}$	-	-100	nA
h _{FE}	DC current gain	$I_{C} = -1 \text{ mA}; V_{CE} = -6 \text{ V}$	120	-	
V _{CEsat}	collector-emitter saturation voltage	$I_{\rm C} = -50$ mA; $I_{\rm B} = -5$ mA; note 1	-	-200	mV
Cc	collector capacitance	I _E = i _e = 0; V _{CB} = -12 V; f = 1 MHz	-	2.2	pF
f _T	transition frequency	$I_{C} = -2 \text{ mA}; V_{CE} = -12 \text{ V}; \text{ f} = 100 \text{ MHz}$	100	-	MHz

Note

1. Pulse test: $t_p \leq 300 \ \mu s; \ \delta \leq 0.02.$

PACKAGE OUTLINE





Product specification

SOT363

PUMT1

DATA SHEET STATUS

DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A.

Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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Contact information

For additional information please visit http://www.semiconductors.philips.com. Fax: +31 40 27 24825 For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

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